

Parameter	Rating	Units
Blocking Voltage	60	V _P
Load Current	4	A _{DC}
On-Resistance (max)	0.09	Ω

Features

- Handle Load Currents Up to 4A_{DC}
- 2500V_{rms} Input/Output Isolation
 Power SIP Package
- High Reliability
- Low Drive Power Requirements
- No EMI/RFI Generation

Applications

- Industrial Controls
- Motor Control
- Robotics
- Medical Equipment—Patient/Equipment Isolation
- Instrumentation
- Multiplexers
- Data Acquisition
- Electronic Switching
- I/O Subsystems
- Meters (Watt-Hour, Water, Gas)
- IC Equipment
- Home Appliances

Description

IXYS Integrated Circuits brings OptoMOS® technology, reliability, and compact size to a new family of high power solid state relays. The CPC1706Y, a DC-switching, normally open (1-Form-A) Solid State Relay, is part of that family.

Employing optically coupled MOSFET technology, the CPC1706Y provides $2500V_{rms}$ of input to output isolation. The relay output is constructed with efficient MOSFET switches that use IXYS Integrated Circuits' patented OptoMOS architecture. The input, a highly efficient infrared LED, controls the optically coupled output.

The combination of low on-resistance and high load current handling capability makes this relay suitable for a variety of high performance switching applications.

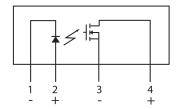
Approvals

UL 508 Certified Component: File E69938

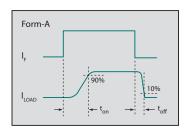
Ordering Information

Part #	Description
CPC1706Y	4-Pin (8-Pin Body) Power SIP Package (25 per tube)

Pin Configuration



Switching Characteristics of **Normally Open Devices**











Absolute Maximum Ratings @ 25°C

Parameter	Symbol	Rating	Unit
Blocking Voltage	V_L	60	V_P
Reverse Input Voltage	V _R	5	V
Input control Current	I _F	50	mA
Peak (10ms)	'F	1	Α
Input Power Dissipation ¹	P _{IN}	150	mW
Total Power Dissipation ²	P _T	2400	mW
Isolation Voltage, Input to Output	V _{ISO}	2500	$V_{\rm rms}$
Operational Temperature, Ambient	T _A	-40 to +85	°C
Storage Temperature	T _{STG}	-40 to +125	°C

¹ Derate linearly 1.33 mW / °C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Typical values are characteristic of the device at +25°C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manufacturing testing requirements.

Electrical Characteristics @ 25°C (Unless Otherwise Noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Units
Output Characteristics						
Blocking Voltage	I _L =1μΑ	V_{DRM}	60	-	-	V
Load Current	Free Air, I _F =5mA					
Continuous	-	IL	-	-	4	A _{DC}
Peak	t=10ms	I _{LPK}	-	-	9	Α
On-Resistance ¹	I _F =5mA, I _L =1A	R _{ON}	-	0.07	0.09	Ω
Off-State Leakage Current	I _F =0mA, V _L =60V _P	I _{LEAK}	-	-	1	μΑ
Switching Speeds						
Turn-On	I _F =5mA, V ₁ =10V	t _{on}	-	0.5	5	ms
Turn-Off	1 _F =311A, V _L =10V	t _{off}	-	0.085	2	1115
Output Capacitance	I _F =0mA, V _L =50V, f=1MHz	C _{OUT}	-	75	-	pF
Input Characteristics						
Input Control Current to Activate	I _L =1A	I _F	-	1.4	5	mA
Input Control Current to Deactivate	-	I _F	0.4	-	-	mA
Input Voltage Drop	I _F =5mA	V _F	0.9	1.36	1.5	V
everse Input Current V _R =5V		I _R	-	-	10	μΑ
Input/Output Characteristics						
Capacitance Input-to-Output	V _{IO} =0V, f=1MHz	C _{IO}	-	2	-	pF

¹ Measurement taken within 1 second of on-time.

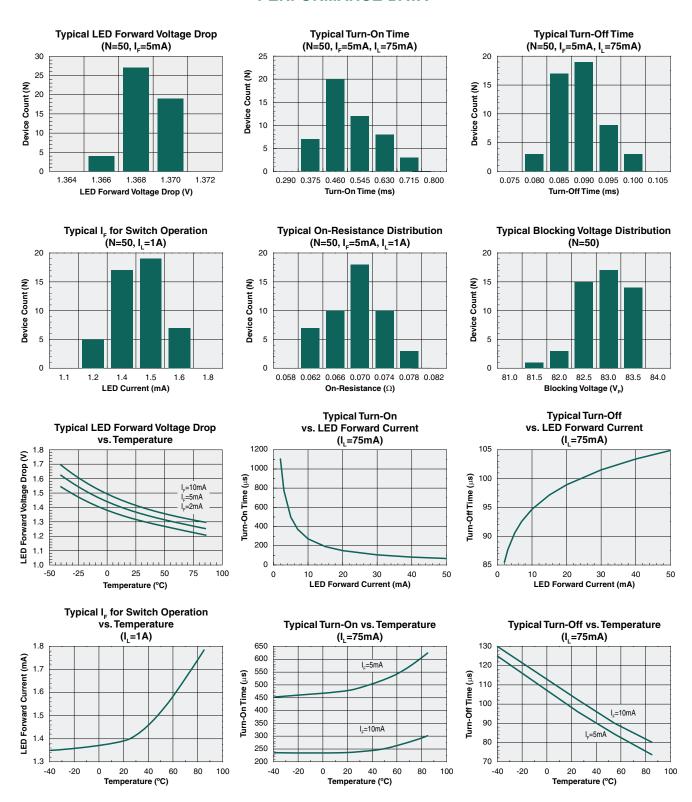
Thermal Characteristics

Parameter	Conditions	Symbol	Rating	Units
Thermal Impedance (junction to case)	-	$\theta_{\sf JC}$	1.5	°C/W

² Derate output power linearly 20 mW / °C



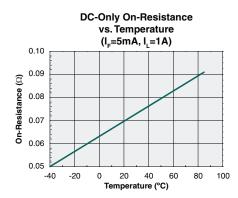
PERFORMANCE DATA*

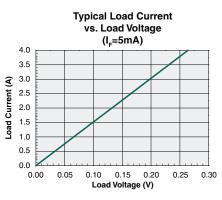


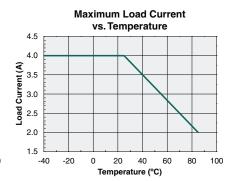
^{*}Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C.

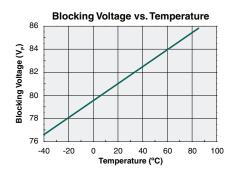


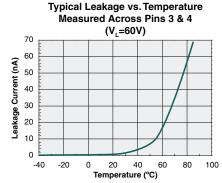
PERFORMANCE DATA*

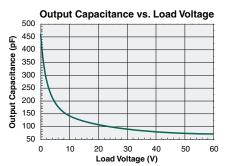


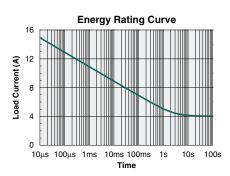












*Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C.



Manufacturing Information

ESD Sensitivity



This product is ESD Sensitive, and should be handled according to the industry standard JESD-625.

Soldering Profile

The Maximum Solder Temperature and the Maximum Total Dwell Time in all solder waves the device pins (leads) may be at the Maximum Solder Temperature is given in the table below. The body temperature of the device must not exceed the Maximum Body Temperature shown below at any time during the soldering process.

Device	Maximum Solder Temperature	Maximum Body Temperature	Maximum Total Dwell Time	Wave Cycles
CPC1706Y	260°C	245°C	10 seconds	1

Board Wash

IXYS Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

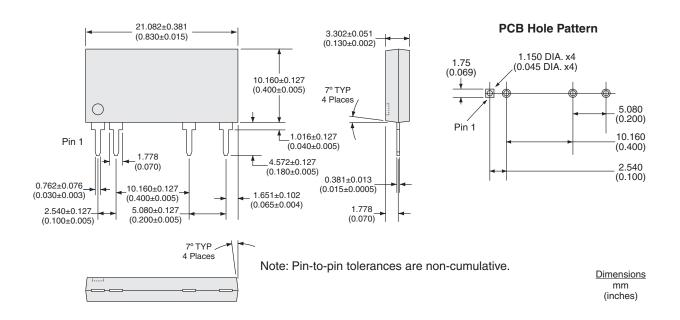








MECHANICAL DIMENSIONS



For additional information please visit our website at: https://www.ixysic.com



Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at https://www.littelfuse.com/disclaimer-electronics.